TVS Diodes Transient Voltage Suppression Diodes

SPC3 Series (3 kA)



Description

The SPC3 in SMTO-218 package provide the enhanced quality, easy manufacturing than typical through-hole TVS components. They can be connected in series and/or parallel to create various capability and flexible protection solutions.

Applications

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- Automotive Electronics
- New Energy
- Lightning Protection

Functional Diagram



Bi-Directional

Features

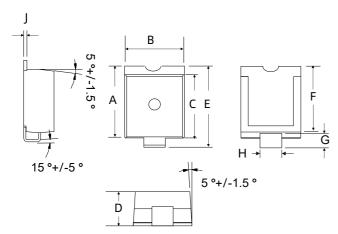
- Bi-directional
- Low clamping and slope resistance
- For automatic pick and place assembly and reflow process to reduce the manufacturing cost and increase the soldering quality compared to axial leads package
- Patent pending package design
- Meet MSL level 1, per J-STD-020, LF Maximum peak of 245 °C
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin (Sn)
- ESD follow IEC 61000-4-2
- Surge protection of lightning in accordance with IEC61000-4-5
- Halogen free and RoHS compliant
- Tube or tape and reel pack options available

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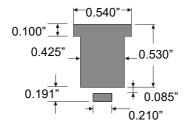
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Package Outline Dimensions (SMTO-218)



Note: Coplanarity of solder side is controlled within 0.10mm



Mounting Pad Layout (Inch)

Ob l	Millim	eters	Inches			
Symbol	Min.	Max.	Min.	Max.		
А	15.78	16.63	0.621	0.655		
В	13.43	15.09	0.529	0.594		
С	13.83	14.24	0.544	0.561		
D	6.94	7.24	0.273	0.285		
E	17.82	18.72	0.702	0.737		
F	14.40	14.76	0.567	0.581		
G	1.88	2.84	0.074	0.112		
Н	4.89	5.65	0.193	0.222		
J	0.72	0.85	0.028	0.033		

Maximum Ratings and Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Storage Temperature Range	T _{STG}	-55 to 150	°C
Operating Junction	TJ	-55 to 125	°C
Current Rating (8/20 µs wave)	I _{PP}	3	kA

Physical Specifications

Weight	Contact manufacturer
Case	Epoxy molding compound encapsulated
Terminal	Tin plated lead, solderability per MIL-STD-202 Method 208

TVS Diodes

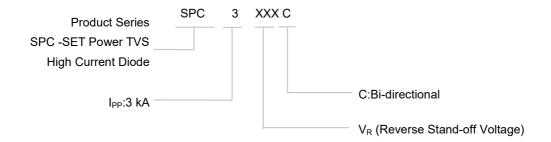
Transient Voltage Suppression Diodes

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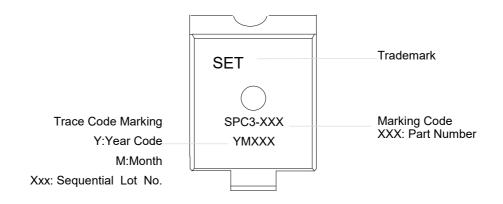
Environmental Specifications

Temperature Cycling	JESD22-A104			
HTRB	JESD22-A108			
MSL	JESDEC-J-STD-020, Level 1			
H3TRB	JESD22-A101			
RSH	JESD22-B106			

Part Numbering System



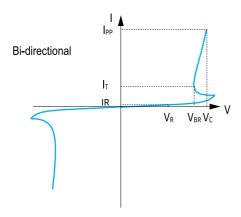
Marking



Electrical Characteristics (T_A=25 °C unless otherwise noted)

Part Number	Stand-off Voltage	Max. Reverse	Breakdown Voltage V₅⊪@I₁ Min Max		Test Current			Voltage V _{CL} Current (I _{PP})	Max. Temp Coefficient	Max. Capacitance	
	V _R	Leakage I _R @V _R					I _{PP} (8/20 μs)	Ι _{ΡΡ} (10/350 μs)	of V _{BR}	0 Bias 10KHz	
			Min	Max			Min	Typical	-		
	(V)	(μΑ)	(V)		(uA)	(V)	(A)	(A)	(%/°C)	(nF)	
SPC3-066C	66	10	75	83	40	120	3000	800	0.1	6	

I-V Curve Characteristics



Performance Curve for Reference(T_A=25 °C unless otherwise noted)

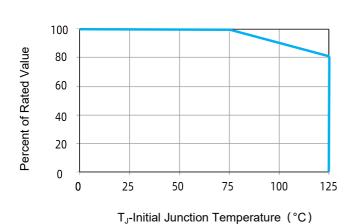


FIGURE 1 Peak Power Derating

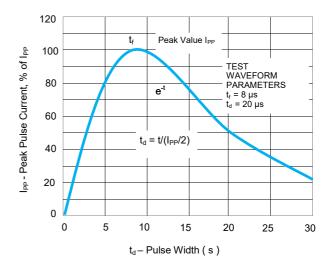
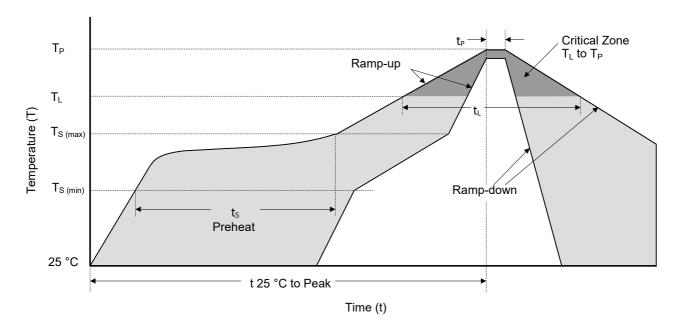


FIGURE 2 Pulse Waveform

Soldering Parameters





Reflowing Condition

Reflow Soldering	Lead-Free Assembly				
	Temperature Min (T _{S (min)})	150 °C			
Pre-heat	Temperature Max (T _{S (max)})	200 °C			
	Time (min to max) (t _s)	60 ~ 120 seconds			
Average Ramp Up Rate (L	3 °C / second max.				
T _S (max) to T _L	T _S (max) to T _L Ramp-up Rate				
D #	Temperature (T _L) (Liquidus)	217 °C			
Reflow	Time (min to max) (t _L)	60 ~ 150 seconds			
Peak Tempe	erature (T _P)	245 ^{+0/-5} °C			
Time of within 5 °C of Acti	ual Peak Temperature (t _P)	20 ~ 40 seconds			
Ramp-do	wn Rate	6 °C / second max.			
Time from 25 °C to	Time from 25 °C to Peak Temperature				
Do Not	245 °C				

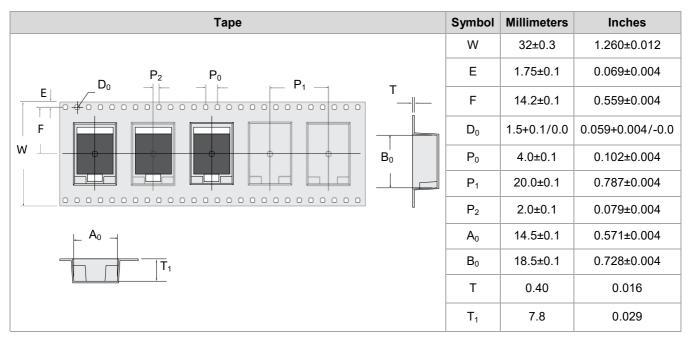
Wave Soldering (Solder Dipping)

Peak Temperature	260 °C+0 /- 5 °C
Dipping Time	10 seconds
Soldering Number	1 time



Transient Voltage Suppression Diodes

Packaging Information



Reel Size	Symbol	Inches	Millimeters
D1	D	Ф13.0	Ф330.0
D	D_1	Ф0.520±0.008	Ф13.2±0.2
Direction of Feed	W ₁	1.417±0.079	36.0±2.0

Part Number	Weight (Typical)	Packaging Option	QTY's
SPC3-XXXXC	4.33 g	Tape & Reel – 32 mm/13" tape	400 PCS

TVS Diodes Transient Voltage Suppression Diodes

Glossary

Item	Description
V _C	Clamping Voltage Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.
V _R	Reverse Stand-off Voltage Maximum voltage that can be applied to the TVS without operation. NOTE: It is also shown as V_{WM} (maximum working voltage (maximum d.c. voltage)) and known as rated stand-off voltage (V_{so}).
I _R	Reverse Leakage Current Current measured at $V_{R.}$ NOTE : Also shown as I_{D} for stand-by current.
V _{BR}	Breakdown Voltage Voltage across TVS at a specified current I_T in the breakdown region.
I _{PPM}	Rated Random Recurring Peak Impulse Current Maximum-rated value of random recurring peak impulse current that may be applied to a device.
P _{M(AV)}	Rated Average Power Dissipation Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.
P _{PPM}	Rated Random Recurring Peak Impulse Power Dissipation Maximum-rated value of the product of rated random recurring peak impulse current (I_{PPM}) multiplies by specified maximum clamping voltage (V_{C}).
Сл	Capacitance Capacitance across the TVS measured at a specified frequency and voltage.
V _{FS}	Peak Forward Surge Voltage Peak voltage across an TVS for a specified forward surge current (I_{FS}) and time duration. NOTE: Also shown as $V_{F.}$
I _{FS}	Forward Surge Current Pulsed current through TVS in the forward conducting region. NOTE: Also shown as I _{F.}
$a_{V(BR)}$	Temperature Coefficient of Breakdown Voltage The change of breakdown voltage divided by the change of temperature.
I _{PP}	Peak pulse Current Peak pulse current value applied across the TVS to determine the clamping voltage $V_{\mathbb{C}}$ for a specified wave shape.
I T	Pulsed D.C. Test Current Test current for measurement of the breakdown voltage $V_{\rm BR}$. This is defined by the manufacturer and usually given in milliamperes with a pulse duration of less than 40 ms. NOTE: Also shown as $I_{\rm BR}$.

--(GB-T 18802.321 / IEC 61643-321 / JESD210A)

TVS Diodes Transient Voltage Suppression Diodes

SPC3 Series (3 kA)



Usage

- TVS must be operated in the specified ambient temp.
- Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

Replacement

- If TVS is visually damaged, please replace it.
- TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

Storage

- 1. Storage Temp. Range: (-55 to 150) °C.
- Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

Environmental Conditions

- 1. TVS should not be exposed to the open air, nor direct sunshine.
- 2. TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- TVS should avoid sand dust, salt mist, or other harmful gases.

Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

Installation Mechanical Stress

- 1. Do not knock TVS when installing, to avoid mechanical damage.
- 2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.

TVS Diodes

Transient Voltage Suppression Diodes

SPC3 Series (3 kA)

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	DO-221AC	0	0	0	0	0	SMA6L	0	0	0	
be	DO-214AA	0	0	0	0	0	0	SACB	SMBJ	P6SMB	
Package Type	DO-214AB										Series
ckag	DO-214AC	0	0	SMAJ	P4SMA	SMA6J	0	0	0	0	ies
Ра	SOD-123FL	SMF	P4SMF								
	SMTO-218	0	0	0	0	0	0	0	0	0	\rightarrow
Proc	duct Outline (mm)	1.30	3.65		5.04		5.20		5.40		
V F Revers	R / V _{WM} (V) e Stand-off Voltage	5.0 ~ 250	5.0 ~ 85	5.0 ~ 440	5.8 ~ 468	5.0 -	~ 250	5.0 ~ 50	5.0 ~ 440	5.8 ~ 512	
(1 (PPPM (W) 0/1000 µs) ed Peak ImPulse wer Dissipation	200		400		600 5		500	60	00	
PPM (Rated P	(kA)(8/20 µs) eak ImPulse Current					0					
C Te	operating mperature (°C)	-55 to +150									

TVS Diodes

Transient Voltage Suppression Diodes

Transient Voltage Suppressor (Surface Mount) Features Overview

	1	\	(-	,						,	^
	DO-221AC	0	0	0	0	0	0	0	0	0	
be	DO-214AA	0	0	0	0	0	0	0	0	0	
Package Type	DO-214AB	SMCJ	1.5SMC	3.0SMCJ	SMDJ	5.0SMDJ			0		Series
ckag	DO-214AC	0	0	0	0	0	0	0	0	0	ies
Pa	SOD-123FL								0		
	SMTO-218	0	0	0	0	0	SPC1	SPC3	SPC6	SPC10	→
Proo	duct Outline (mm)	7.94					18.27				
V i Revers	R / V _{WM} (V) se Stand-off Voltage	5.0 ~ 440	5.8 ~ 512	5.0 ~	- 440	12 ~ 170	380 / 430	66	58 ~ 76	58 ~ 86	
(10 Rate Po	PPPM (W) 0/1000 μs) ed Peak ImPulse wer Dissipation	1500 3000 5000					0				
PPM (Rated P	(kA)(8/20 µs) eak ImPulse Current	0					1	3	6	10	
C Te	Operating mperature (°C)	-55 to +150						-55 to	o +125		

Transient Voltage Suppressor (Axial Lead) Features Overview

	/	\															
	DO-201	0	0	0	1.5KE	LCE	0	0	0	0	0	0	0	0	0	0	
Гуре	DO-41	P4KE															Series
Package Type	DO-15	0	SAC	P6KE	0	0	0	0	0	0	0	0	0	0	0	0	
Pack	P600	0					5KP	15KPA	20KPA	30KPA							
F	Radial lead	0	0	0	0	0	0	0	0	0	SPCL1	SPCL3	SPCL6	SPCL10	SPCL15	SPCL20	
Product Outline (mm)		8.200 ± 4.65 ± 42.35 ± 42.35 ± 42.35	ф3.10 02 6 ф0.78	57.50	Φ5.05 → Ω _ε ∞ Φ1.00	59.15		Ф8.85 98.85 Ф1.28	59.65		12.70	17.00	2	0.48	14.50	2.00	
V _R /	V_{WM} (V) Stand-off Voltage	5.8 ~ 468	5.0 ~ 50	5.8 ~ 512	5.8 ~ 512	6.5 ~ 90	5.0 ~ 250	17 ~ 280	20 ~ 300	28 ~ 360	76	15 ~ 430	30 ~ 430	15 ~ 530	58 ~ 380	16 ~ 76	
(10/ Rated Powe	PPM (W) 1000 µS) Peak ImPulse er Dissipation	400 500 600			1500		5000	15000 20000 30000		30000	0						
PPM (K Rated Pea	A)(8/20 µs) k ImPulse Current	0										3	6	10	15	20	
Tem	perating operature (°C)	-55 to +150								-55 to +125							